

Nimmakayala V V Subbarao

List of Publications by Year in descending order

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9
papers

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| # | ARTICLE | IF | CITATIONS |
|---|---|-----|-----------|
| 1 | Effects of Dielectric Material, HMDS Layer, and Channel Length on the Performance of the Perylenediimide-Based Organic Field-Effect Transistors. ACS Omega, 2017, 2, 2552-2560. | 3.5 | 14 |
| 2 | Low voltage, low cost, flexible and balanced ambipolar OFETs based on Br ₂ PTCDI-C18/CuPc fabricated on an Al foil gate substrate with good ambient stability. Journal of Materials Chemistry C, 2016, 4, 7102-7109. | 5.5 | 20 |
| 3 | Large-Scale Molecular Packing and Morphology-Dependent High Performance Organic Field-Effect Transistor by Symmetrical Naphthalene Diimide Appended with Methyl Cyclohexane. Journal of Physical Chemistry C, 2015, 119, 12772-12779. | 3.1 | 20 |
| 4 | Enhanced Environmental Stability Induced by Effective Polarization of a Polar Dielectric Layer in a Trilayer Dielectric System of Organic Field-Effect Transistors: A Quantitative Study. ACS Applied Materials & Interfaces, 2015, 7, 1915-1924. | 8.0 | 56 |
| 5 | Vapor phase sensing of ammonia at the sub-ppm level using a perylene diimide thin film device. Journal of Materials Chemistry C, 2015, 3, 10767-10774. | 5.5 | 74 |
| 6 | Effect of thickness of bilayer dielectric on 1,7-dibromo-N,N'-di-octadecyl-3,4,9,10-perylenetetracarboxylic diimide based organic field-effect transistors. Physica Status Solidi (A) Applications and Materials Science, 2014, 211, 2403-2411. | 1.8 | 6 |
| 7 | Local Diffusion Induced Roughening in Cobalt Phthalocyanine Thin Film Growth. Langmuir, 2014, 30, 8735-8740. | 3.5 | 18 |
| 8 | Growth mechanism of Cobalt(II) Phthalocyanine(CoPc) thin films on SiO ₂ and muscovite substrates., 2014, , . | | 3 |
| 9 | High carrier mobility of CoPc wires based field-effect transistors using bi-layer gate dielectric. AIP Advances, 2013, 3, 112123. | 1.3 | 8 |